

Switchmode Rf And Microwave Power Amplifiers

"Do you want to design a wireless transmitter or receiver for hand-held telephones? Have you wondered why the printed circuit wires on high-frequency circuits don't always run in a straight line? This valuable text will answer all of your questions regarding component parasitics and circuit characterization for rf/microwave amplifier, oscillator, and filter circuit design and analysis. You will understand why capacitors act as inductors and vice versa and why amplifiers work like oscillators, while oscillators for local area networks work more like local area heaters. Application of the information in Introduction to Microwave Circuits will reduce design-cycle time and costs, markedly increasing the probability of first-time success in printed circuit or monolithic microwave integrated circuit (MMIC) design. Several approaches are taken into consideration, such as the effects of currents on the ground plane, bypass and coupling capacitors, and nonlinear effects in linear circuits. Featured topics include: * Incorporation of component parasitics in the design cycle * Closed form solution to oscillator design * Odd mode stability analysis * PIN diode analysis for high-power switching applications An integrated design example of a 1.25 GHz amplifier, oscillator, and filter printed circuit is also included, which could be useful in printed circuit board designs from tens of megahertz to tens of gigahertz. Introduction to Microwave Circuits provides the tools necessary to analyze or synthesize microwave circuits. This text is an essential reference for undergraduate students, microwave engineers, and administrators. Also, it will assist experienced designers in other fields to meet the current rapid expansion of communication system applications and work effectively in microwave circuit design. About the Author Robert J. Weber began his prolific career in the Solid State Research Laboratory at the Collins Radio Company, later a part of Rockwell International. For 25 years, he worked on advanced development and applied research in the one- to ten-gigahertz frequency range and received several distinguished awards for his valuable contributions to the field. Dr. Weber is involved in ongoing experimental research in integrating microwave circuits with other devices such as MEMS, chemical sensors, and electro-optics. Also, he teaches microwave circuit design and fiber-optics communications at the Department of Electrical and Computer Engineering, Iowa State University. Dr. Weber is an IEEE Fellow." Sponsored by: IEEE Microwave Theory and Techniques Society.

Doherty Power Amplifiers: From Fundamentals to Advanced Design Methods is a great resource for both RF and microwave engineers and graduate students who want to understand and implement the technology into future base station and mobile handset systems. The book introduces the very basic operational principles of the Doherty Amplifier and its non-ideal behaviors. The different transconductance requirements for carrier and peaking amplifiers, reactive element effect, and knee voltage effect are described. In addition, several methods to correct imperfections are introduced, such as uneven input drive, gate bias adaptation, dual input drive and the offset line technique. Advanced design methods of Doherty Amplifiers are also explained, including multistage/multiway Doherty power amplifiers which can enhance the efficiency of the amplification of a highly-modulated signal. Other covered topics include signal tracking operation which increases the dynamic range, highly efficient saturated amplifiers, and broadband amplifiers, amongst other comprehensive, related topics. Specifically written on the Doherty Power Amplifier by the world's leading expert, providing an in-depth presentation of principles and design techniques Includes detailed analysis on correcting non-ideal behaviors of Doherty Power Amplifiers Presents advanced Doherty Power Amplifier architectures

The ultimate handbook on microwave circuit design with CAD. Full of tips and insights from seasoned industry veterans, Microwave Circuit Design offers practical, proven advice on improving the design quality of microwave passive and active circuits-while cutting costs and time. Covering all levels of microwave circuit design from the elementary to the very advanced, the book systematically presents computer-aided methods for linear and nonlinear designs used in the design and manufacture of microwave amplifiers, oscillators, and mixers. Using the newest CAD tools, the book shows how to design transistor and diode circuits, and also details CAD's usefulness in microwave integrated circuit (MIC) and monolithic microwave integrated circuit (MMIC) technology. Applications of nonlinear SPICE programs, now available for microwave CAD, are described. State-of-the-art coverage includes microwave transistors (HEMTs, MODFETs, MESFETs, HBTs, and more), high-power amplifier design, oscillator design including feedback topologies, phase noise and examples, and more. The techniques presented are illustrated with several MMIC designs, including a wideband amplifier, a low-noise amplifier, and an MMIC mixer. This unique, one-stop handbook also features a major case study of an actual anticollision radar transceiver, which is compared in detail against CAD predictions; examples of actual circuit designs with photographs of completed circuits; and tables of design formulae.

Do you want to know how to design high efficiency RF and microwave solid state power amplifiers? Read this book to learn the main concepts that are fundamental for optimum amplifier design. Practical design techniques are set out, stating the pros and cons for each method presented in this text. In addition to novel theoretical discussion and workable guidelines, you will find helpful running examples and case studies that demonstrate the key issues involved in power amplifier (PA) design flow. Highlights include: Clarification of topics which are often misunderstood and misused, such as bias classes and PA nomenclatures. The consideration of both hybrid and monolithic microwave integrated circuits (MMICs). Discussions of switch-mode and current-mode PA design approaches and an explanation of the differences. Coverage of the linearity issue in PA design at circuit level, with advice on low distortion power stages. Analysis of the hot topic of Doherty amplifier design, plus a description of advanced techniques based on multi-way and multi-stage architecture solutions. High Efficiency RF and Microwave Solid State Power Amplifiers is: an ideal tutorial for MSc and postgraduate students taking courses in microwave electronics and solid state circuit/device design; a useful reference text for practising electronic engineers and researchers in the field of PA design and microwave and RF engineering. With its unique unified vision of solid state amplifiers, you won't find a more comprehensive publication on the topic.

A practically based explanation of electronic circuitry.

A majority of people now have a digital mobile device whether it be a cell phone, laptop, or blackberry. Now that we have the mobility we want it to be more versatile and dependable; RF power amplifiers accomplish just that. These amplifiers take a small input and make it stronger and larger creating a wider area of use with a more robust signal. Switching mode RF amplifiers have been theoretically possible for decades, but were largely impractical because they distort analog signals until they are unrecognizable. However, distortion is not an issue with digital signals—like those used by WLANs and digital cell phones—and switching mode RF amplifiers have become a hot area of RF/wireless design. This book explores both the theory behind

switching mode RF amplifiers and design techniques for them. *Provides essential design and implementation techniques for use in cma2000, WiMAX, and other digital mobile standards

*Both authors have written several articles on the topic and are well known in the industry *Includes specific design equations to greatly simplify the design of switchmode amplifiers

This comprehensive resource explains the theory of RF circuits and systems and the practice of designing them. The fundamentals for linear and low noise amplifier designs, including the S and noise parameters and their applications in amplifier designs and matching network designs using the Smith chart are covered. Theories of RF power amplifiers and high efficiency power amplifiers are also explained. The underpinnings of wireless communications systems as well as passive components commonly used in RF circuits and measurements are discussed. RF measurement techniques and RF switches are also presented. The book explores stability criteria and the invariant property of lossless networks and includes detailed theoretical treatments. The basic concepts and techniques covered in this book are routinely used in today's engineering practice, especially from the perspective of printed circuit board (PCB) based RF circuit design and system integration. Intended for practicing engineers and circuit designers, this book focuses on practical topics in circuit design and measurement techniques. It bridges the gap between academic materials and real circuit designs using real circuit examples and practical tips. Readers develop a numerical feel for RF problems as well as awareness of the concepts of design for cost and design for manufacturing, which is a critical skill set for today's engineers working in an environment of commercial product development.

Cellular telephones, satellite communications and radar systems are adding to the increasing demand for radio frequency circuit design principles. At the same time, several generations of digitally-oriented graduates are missing the essential RF skills. This book contains a wealth of valuable design information difficult to find elsewhere. It's a complete 'tool kit' for successful RF circuit design. Written by experienced RF design engineers from Motorola's semiconductors product section. Book covers design examples of circuits (e.g. amplifiers; oscillators; switches; pulsed power; modular systems; wiring state-of-the-art devices; design techniques).

The introduction of Li-ion batteries in 1991 created a tremendous change in the handheld devices landscape. Since then, the energy stored and put to use in palm-sized electronic devices has quadrupled. Devices are continuously getting more power hungry, outpacing battery development. Written by leading engineers in the field, This cutting-edge resource helps you overcome this challenge, offering you an insightful overview and in-depth guide to the many varied areas of battery power management for portable devices. You find the latest details on optimizing charging circuits, developing battery gauges that provide the longest possible run-time while ensuring data protection, and utilizing safety circuits that provide multiple independent levels of protection for highly energetic batteries. This unique book features detailed design examples of whole systems, providing you with the real-world perspective needed to put this knowledge into practice. You get the state-of-the-art know-how you need to perfect your device designs, helping you make them strong competitors in the fast-growing portable device marketplace.

This book provides a system-level approach to making packaging decisions for millimeter-wave transceivers. In electronics, the packaging forms a bridge between the integrated circuit or individual device and the rest of the electronic system, encompassing all technologies between the two. To be able to make well-founded packaging decisions, researchers need to understand a broad range of aspects, including: concepts of transmission bands, antennas and propagation, integrated and discrete package substrates, materials and technologies, interconnects, passive and active components, as well as the advantages and disadvantages of various packages and packaging approaches, and package-level modeling and simulation. Packaging also needs to be considered in terms of system-level testing, as well as associated testing and production costs, and reducing costs. This peer-reviewed work contributes to the extant scholarly literature by addressing the aforementioned concepts and applying them to the context of the millimeter-wave regime and the unique opportunities that this transmission approach offers.

Broadband RF and Microwave Amplifiers provides extensive coverage of broadband radio frequency (RF) and microwave power amplifier design, including well-known historical and recent novel schematic configurations, theoretical approaches, circuit simulation results, and practical implementation strategies. The text begins by introducing two-port networks to illustrate the behavior of linear and nonlinear circuits, explaining the basic principles of power amplifier design, and discussing impedance matching and broadband power amplifier design using lumped and distributed parameters. The book then: Shows how dissipative or lossy gain-compensation-matching circuits can offer an important trade-off between power gain, reflection coefficient, and operating frequency bandwidth Describes the design of broadband RF and microwave amplifiers using real frequency techniques (RFTs), supplying numerous examples based on the MATLAB® programming process Examines Class-E power amplifiers, Doherty amplifiers, low-noise amplifiers, microwave gallium arsenide field-effect transistor (GaAs FET)-distributed amplifiers, and complementary metal-oxide semiconductor (CMOS) amplifiers for ultra-wideband (UWB) applications Broadband RF and Microwave Amplifiers combines theoretical analysis with practical design to create a solid foundation for innovative ideas and circuit design techniques.

This second edition of the highly acclaimed RF Power Amplifiers has been thoroughly revised and expanded to reflect the latest challenges associated with power transmitters used in communications systems. With more rigorous treatment of many concepts, the new edition includes a unique combination of class-tested analysis and industry-proven design techniques. Radio frequency (RF) power amplifiers are the fundamental building blocks used in a vast variety of wireless communication circuits, radio and TV broadcasting transmitters, radars, wireless energy transfer, and industrial processes. Through a combination of theory and practice, RF Power Amplifiers, Second Edition provides a solid understanding of the key concepts, the principle of operation, synthesis, analysis, and design of RF power amplifiers. This extensive update boasts: up to date end of chapter summaries; review questions and problems; an expansion on key concepts; new examples related to real-world applications illustrating key concepts and brand new chapters covering 'hot topics' such as RF LC oscillators and dynamic power supplies. Carefully edited for superior readability, this work remains an essential reference for

research & development staff and design engineers. Senior level undergraduate and graduate electrical engineering students will also find it an invaluable resource with its practical examples & summaries, review questions and end of chapter problems. Key features:

- A fully revised solutions manual is now hosted on a companion website alongside new simulations.
- Extended treatment of a broad range of topologies of RF power amplifiers.
- In-depth treatment of state-of-the art of modern transmitters and a new chapter on oscillators.
- Includes problem-solving methodology, step-by-step derivations and closed-form design equations with illustrations.

"Power is dissipated (lost) when this current flows through any resistance, which includes the amplifier's transistor. This dissipated power is the product of the current in the load times the voltage difference between the supply voltage to the amplifier and the output signal voltage. When the voltage supplied to the amplifier is a constant value, and by far the most common design practice, the situation in Fig. 1-2a results. Power dissipation in the amplifier is maximum when the output signal voltage is 1/2 of the supply voltage. When the output signal voltage is higher, even though the current value is larger the voltage drop is less and the power dissipation is lower. Similarly, when the output signal voltage is small, even though the voltage drop is now large the current in the load is smaller and again the power dissipation is lower"--

As technology matures, communication system operation regions shift from mic- wave and millimeter ranges to sub-millimeter ranges. However, device performance at very high frequencies suffers drastically from the material deficiencies. As a result, engineers and scientists are relentlessly in search for the new types of materials, and composites which will meet the device performance requirements and not present any deficiencies due to material electrical and magnetic properties. Anisotropic and gyrotropic materials are the class of the materials which are very important in the development high performance microwave devices and new types composite layered structures. As a result, it is a need to understand the wave propagation and radiation characteristics of these materials to be able to realize them in practice. This book is intended to provide engineers and scientists the required skill set to design high frequency devices using anisotropic, and gyrotropic materials by providing them the theoretical background which is blended with the real world engineering application examples. It is the author's hope that this book will help to fill the gap in the area of applied electromagnetics for the design of microwave and millimeter wave devices using new types of materials. Each chapter in the book is designed to give the theory first on the subject and solidify it with application examples given in the last chapter. The application examples for the radiation problems are given at the end of Chap. 5 and Chap. 6 for anisotropic and gyrotropic materials, respectively, after the theory section.

This book introduces systematic design methods for passive and active RF circuits and techniques, including state-of-the-art digital enhancement techniques. As the very first book dedicated to multiband RF circuits and techniques, this work provides an overview of the evolution of transmitter architecture and discusses current digital predistortion techniques. Readers will find a collection of novel research ideas and new architectures in concurrent multiband power dividers, power amplifiers and related digital enhancement techniques. This book will be of great interest to academic researchers, R&D engineers, wireless transmitter and protocol designers, as well as graduate students who wish to learn the core architectures, principles and methods of multiband RF circuits and techniques.

A practical approach to RF circuit design, this volume covers nonlinear circuits and modelling, RF transistor amplifiers, oscillators and mixers.

This extensively revised edition offers a comprehensive, practical, up-to-date understanding of how to tackle a power amplifier design with confidence and quickly determine the cause of malfunctioning hardware.

RF power amplifiers are implemented in communication, semiconductor wafer processing, magnetic resonance imaging (MRI), and radar systems to produce RF signal with the desired characteristics to perform several critical tasks in the entire system. They can be designed to operate in linear or switch-mode, depending on the specific application. This book explores the design and implementation methods for both linear and switch-mode amplifiers with real world engineering problems. The text discusses phased controlled switch-mode amplifiers and distortion and modulation effects in RF amplifiers. It illustrates the interface and integration of components and sub-systems for RF amplifiers. The material is further reinforced with MATLAB design files.

Switchmode RF and Microwave Power Amplifiers, Third Edition is an essential reference book on developing RF and microwave switchmode power amplifiers. The book combines theoretical discussions with practical examples, allowing readers to design high-efficiency RF and microwave power amplifiers on different types of bipolar and field-effect transistors, design any type of high-efficiency switchmode power amplifiers operating in Class D or E at lower frequencies and in Class E or F and their subclasses at microwave frequencies with specified output power, also providing techniques on how to design multiband and broadband Doherty amplifiers using different bandwidth extension techniques and implementation technologies. This book provides the necessary information to understand the theory and practical implementation of load-network design techniques based on lumped and transmission-line elements. It brings a unique focus on switchmode RF and microwave power amplifiers that are widely used in cellular/wireless, satellite and radar communication systems which offer major power consumption savings. Provides a complete history of high-efficiency Class E and Class F techniques Presents a new chapter on Class E with shunt capacitance and shunt filter to simplify the design of high-efficiency power amplifier with broader frequency bandwidths Covers different Doherty architectures, including integrated and monolithic implementations, which are and will be, used in modern communication systems to save power consumption and to reduce size and costs Includes extended coverage of multiband and broadband Doherty amplifiers with different frequency ranges and output powers using different bandwidth extension techniques Balances theory with practical implementation, avoiding a cookbook approach and enabling engineers to develop better designs,

including hybrid, integrated and monolithic implementations

The book presents fundamentals of communication electronic circuits, including structure, principle, analyzing methodology, design and design software. Radio frequency amplifier, sinusoidal oscillator, amplitude modulation and demodulation, angular modulation and demodulation are described in detail. The book serves for learning and teaching but can also help researchers and professionals as reference.

This is a rigorous tutorial on radio frequency and microwave power amplifier design, teaching the circuit design techniques that form the microelectronic backbones of modern wireless communications systems. Suitable for self-study, corporate training, or Senior/Graduate classroom use, the book combines analytical calculations and computer-aided design techniques to arm electronic engineers with every possible method to improve their designs and shorten their design time cycles.

This book explores up-to-date research trends and achievements on low-power and high-speed technologies in both electronics and optics. It offers unique insight into low-power and high-speed approaches ranging from devices, ICs, sub-systems and networks that can be exploited for future mobile devices, 5G networks, Internet of Things (IoT), and data centers. It collects heterogeneous topics in place to catch and predict future research directions of devices, circuits, subsystems, and networks for low-power and higher-speed technologies. Even it handles about artificial intelligence (AI) showing examples how AI technology can be combined with concurrent electronics. Written by top international experts in both industry and academia, the book discusses new devices, such as Si-on-chip laser, interconnections using graphenes, machine learning combined with CMOS technology, progresses of SiGe devices for higher-speed electronics for optic, co-design low-power and high-speed circuits for optical interconnect, low-power network-on-chip (NoC) router, X-ray quantum counting, and a design of low-power power amplifiers. Covers modern high-speed and low-power electronics and photonics. Discusses novel nano-devices, electronics & photonic sub-systems for high-speed and low-power systems, and many other emerging technologies like Si photonic technology, Si-on-chip laser, low-power driver for optic device, and network-on-chip router. Includes practical applications and recent results with respect to emerging low-power systems. Addresses the future perspective of silicon photonics as a low-power interconnections and communication applications.

This first book on load-pull systems is intended for readers with a broad knowledge of high frequency transistor device characterization, nonlinear and linear microwave measurements, RF power amplifiers and transmitters. Load-Pull Techniques with Applications to Power Amplifier Design fulfills the demands of users, designers, and researchers both from industry and academia who have felt the need of a book on this topic. It presents a comprehensive reference spanning different load-pull measurement systems, waveform measurement and engineering systems, and associated calibration procedures for accurate large signal characterization. Besides, this book also provides in-depth practical considerations required in the realization and usage of load-pull and waveform engineering systems. In addition, it also provides procedure to design application specific load-pull setup and includes several case studies where the user can customize architecture of load-pull setups to meet any specific measurement requirements. Furthermore, the materials covered in this book can be part of a full semester graduate course on microwave device characterization and power amplifier design.

RF and Microwave Transmitter Design is unique in its coverage of both historical transmitter design and cutting edge technologies. This text explores the results of well-known and new theoretical analyses, while informing readers of modern radio transmitters' practical designs and their components. Jam-packed with information, this book broadcasts and streamlines the author's considerable experience in RF and microwave design and development.

The IET has organised training courses on microwave measurements since 1983, at which experts have lectured on modern developments. Their lecture notes were first published in book form in 1985 and then again in 1989, and they have proved popular for many years with a readership beyond those who attended the courses. The purpose of this third edition of the lecture notes is to bring the latest techniques in microwave measurements to this wider audience. The book begins with a survey of the theory of current microwave circuits and continues with a description of the techniques for the measurement of power, spectrum, attenuation, circuit parameters, and noise. Various other areas like measurements of antenna characteristics, free fields, modulation and dielectric parameters are also included. The emphasis throughout is on good measurement practice. All the essential theory is given and a previous knowledge of the subject is not assumed.

Microwave and RF Design: Radio Systems is a circuits- and systems-oriented approach to modern microwave and RF systems. Sufficient details at the circuits and sub-system levels are provided to understand how modern radios are implemented. Design is emphasized throughout. The evolution of radio from what is now known as 0G, for early radio, through to 6G, for sixth generation cellular radio, is used to present modern microwave and RF engineering concepts. Two key themes unify the text: 1) how system-level decisions affect component, circuit and subsystem design; and 2) how the capabilities of technologies, components, and subsystems impact system design. This book is suitable as both an undergraduate and graduate textbook, as well as a career-long reference book. Key Features * The first volume of a comprehensive series on microwave and RF design * Open access ebook editions are hosted by NC State University Libraries at <https://repository.lib.ncsu.edu/handle/1840.20/36776> * 31 worked examples * An average of 38 exercises per chapter * Answers to selected exercises * Coverage of cellular radio from 1G through 6G * Case study of a software defined radio illustrating how modern radios partition functionality between analog and digital domains * A companion book, Fundamentals of Microwave and RF Design, is suitable as a comprehensive undergraduate textbook on microwave engineering A complete guide, this book presents industrial microwave heating from an engineering base and integrating the essential elements of microwave theory and heat transfer with practical design, application and operational issues.

Build high-performance, energy-efficient circuits with this cutting-edge guide to designing, modeling, analysing, implementing and testing new mm-wave systems.

Introduction to RF Power Amplifier Design and Simulation fills a gap in the existing literature by providing step-by-step guidance for the design of radio frequency (RF) power amplifiers, from analytical formulation to simulation, implementation, and measurement. Featuring numerous illustrations and examples of real-world engineering applications, this book: Gives an overview of intermodulation and elaborates on the difference between linear and nonlinear amplifiers Describes the high-frequency model and transient characteristics of metal-oxide-semiconductor field-effect transistors Details active

device modeling techniques for transistors and parasitic extraction methods for active devices Explores network and scattering parameters, resonators, matching networks, and tools such as the Smith chart Covers power-sensing devices including four-port directional couplers and new types of reflectometers Presents RF filter designs for power amplifiers as well as application examples of special filter types Demonstrates the use of computer-aided design (CAD) tools, implementing systematic design techniques Blending theory with practice, Introduction to RF Power Amplifier Design and Simulation supplies engineers, researchers, and RF/microwave engineering students with a valuable resource for the creation of efficient, better-performing, low-profile, high-power RF amplifiers.

Magnetic resonance imaging, semiconductor processing, and RFID are some of the critical applications within the medium frequency (MF) to ultrahigh frequency (UHF) range that require RF designers to have a solid understanding of analytical and experimental RF techniques. Designers need to be able to design components and devices cost effectively, and integrate them with high efficiency, minimal loss, and required power. Computer-aided design (CAD) tools also play an important part in helping to reduce costs and improve accuracy through optimization. RF Circuit Design Techniques for MF-UHF Applications explains how to design, simulate, and implement RF/microwave components and devices for applications within the medium frequency (MF) to ultrahigh frequency (UHF) range. The book makes RF design simple by expertly blending theory, simulation, and practical application examples. A Practical Guide to RF Circuit Design in the MF-UHF Range: Theory, Simulation, and Real-World Application Examples After a review of network parameters used in the analysis of RF components and devices, the book examines MF-UHF design techniques in detail. These include techniques for designing high-power microstrip circuits, directional couplers, transformers, composite and multilayer inductors, filters, combiners/dividers, and RFID systems. For every device, the book gives the required theory and then explains the verification process with CAD tools. In addition, each design is illustrated with real-life implementation examples that use a variety of CAD tools such as MATLAB®, Mathcad, HFSSTM, Ansoft Designer®, Sonnet®, and PSpice®. Design tables, curves, and charts are included to demonstrate an efficient design process. Throughout, the book also offers practical hints to help engineers shorten the design time. Design MF-UHF Devices More Cost-Effectively The book reflects the optimum design methodology used in RF engineering, from the application of theory, to simulation for verification, to experimentation. Packed with useful techniques, tips, and examples, it is an invaluable resource for engineers, researchers, and students working in the MF-UHF range.

This book is the first standalone book that combines research into low-noise amplifiers (LNAs) with research into millimeter-wave circuits. In compiling this book, the authors have set two research objectives. The first is to bring together the research context behind millimeter-wave circuit operation and the theory of low-noise amplification. The second is to present new research in this multi-disciplinary field by dividing the common LNA configurations and typical specifications into subsystems, which are then optimized separately to suggest improvements in the current state-of-the-art designs. To achieve the second research objective, the state-of-the-art LNA configurations are discussed and the weaknesses of state-of-the-art configurations are considered, thus identifying research gaps. Such research gaps, among others, point towards optimization – at a systems and microelectronics level. Optimization topics include the influence of short wavelength, layout and crosstalk on LNA performance. Advanced fabrication technologies used to decrease the parasitics of passive and active devices are also explored, together with packaging technologies such as silicon-on-chip and silicon-on-package, which are proposed as alternatives to traditional IC implementation. This research outcome builds through innovation. Innovative ideas for LNA construction are explored, and alternative design methodologies are deployed, including LNA/antenna co-design or utilization of the electronic design automation in the research flow. The book also offers the authors' proposal for streamlined automated LNA design flow, which focuses on LNA as a collection of highly optimized subsystems.

This new resource presents readers with all relevant information and comprehensive design methodology of wideband amplifiers. This book specifically focuses on distributed amplifiers and their main components, and presents numerous RF and microwave applications including well-known historical and recent architectures, theoretical approaches, circuit simulation, and practical implementation techniques. A great resource for practicing designers and engineers, this book contains numerous well-known and novel practical circuits, architectures, and theoretical approaches with detailed description of their operational principles.

This book provides a detailed review of power amplifiers, including classes and topologies rarely covered in books, and supplies sufficient information to allow the reader to design an entire amplifier system, and not just the power amplification stage. A central aim is to furnish readers with ideas on how to simplify the design process for a preferred power amplifier stage by introducing software-based routines in a programming language of their choice. The book is in two parts, the first focusing on power amplifier theory and the second on EDA concepts. Readers will gain enough knowledge of RF and microwave transmission theory, principles of active and passive device design and manufacturing, and power amplifier design concepts to allow them to quickly create their own programs, which will help to accelerate the transceiver design process. All circuit designers facing the challenge of designing an RF or microwave power amplifier for frequencies from 2 to 18 GHz will find this book to be a valuable asset.

A comprehensive treatment of microwave radio-frequency amplifier design, using solid-state devices such as GaAs FEETs, microwave bipolar transistors, IMPATT and Gunn diodes. Emphasis is on low-noise, high-gain and high-power transistor amplifiers for both wideband and narrowband applications, using scattering parameters as design tools. Includes computer simulation results of amplifier performance in design examples, problems and an extensive bibliography.

A Comprehensive and Up-to-Date Treatment of RF and Microwave Transistor Amplifiers This book provides state-of-the-art coverage of RF and microwave transistor amplifiers, including low-noise, narrowband, broadband, linear, high-power, high-efficiency, and high-voltage. Topics covered include modeling, analysis, design, packaging, and thermal and fabrication considerations. Through a unique integration of theory and practice, readers will learn to solve amplifier-related design problems ranging from matching networks to biasing and stability. More than 240 problems are included to help readers test their basic amplifier and circuit design skills-and more than half of the problems feature fully worked-out solutions. With an emphasis on theory, design, and everyday applications, this book is geared toward students, teachers, scientists, and practicing engineers who are interested in broadening their knowledge of RF and microwave transistor amplifier circuit design.

This book compiles and presents the research results from the past five years in mm-wave Silicon circuits. This area has received a great deal of interest from the research community including several university and research groups. The book covers device modeling, circuit building blocks, phased array systems, and antennas and packaging. It focuses on the techniques that uniquely take advantage of the scale and integration offered by silicon based technologies.

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